



SI4501BDY-T1-GE3 Information



For Reference Only

Part Number SI4501BDY-T1-GE3
Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET N/P-CH 30V/8V 8SOIC **Package** 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI4501BDY-T1-GE3 Specifications

	Report errors?
Supplier Device Package	8-SOIC
Package / Case	8-SOIC (0.154", 3.90mm Width)
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 150°C (TJ)
Power - Max	4.5W, 3.1W
Input Capacitance (Ciss) (Max) @ Vds	805pF @ 15V
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Vgs(th) (Max) @ Id	2V @ 250μA
Rds On (Max) @ Id, Vgs	17 mOhm @ 10A, 10V
Current - Continuous Drain (Id) @ 25°C	12A, 8A
Drain to Source Voltage (Vdss)	30V, 8V
FET Feature	Logic Level Gate
FET Type	N and P-Channel, Common Drain
Series	TrenchFET?
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SI4501BDY-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4501BDY-T1-GE3 Payment Methods





















SI4501BDY-T1-GE3 Shipping Methods













If you have any question about SI4501BDY-T1-GE3, please do not hesitate to contact us!

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